

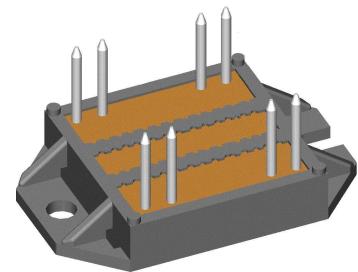
# FRED Module

$V_{RRM}$  = 600 V  
 $I_{FAV}$  = 2x 60 A  
 $t_{rr}$  = 35 ns

Fast Recovery Epitaxial Diode  
Low Loss and Soft Recovery  
Parallel legs

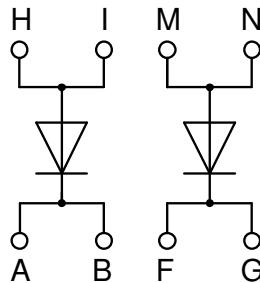
Part number

**DSEI2x61-06P**



Backside: isolated

 E72873



## Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: ECO-PAC1

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

## Disclaimer Notice

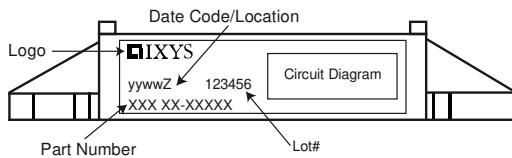
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**Fast Diode**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
$I_R$	reverse current, drain current	$V_R = 600 \text{ V}$ $V_R = 480 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		200 14	$\mu\text{A}$ mA
$V_F$	forward voltage drop	$I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$ $I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.69 1.90 1.43 1.72	V V V V
$I_{FAV}$	average forward current	$T_C = 75^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 150^\circ\text{C}$		60	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		1.16 4.5	V $\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.10		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		180	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		550	A
$C_J$	junction capacitance	$V_R = 600 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		49	pF
$I_{RM}$	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		10 16	A A
$t_{rr}$	reverse recovery time	$I_F = 60 \text{ A}; V_R = 350 \text{ V}$ $-di_F/dt = 400 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		100 180	ns ns

**Package ECO-PAC1**

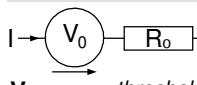
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	RMS current	per terminal			100	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>				19		g
$M_D$	mounting torque		1.4		2	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	6.0			mm
$d_{Spb/Apb}$		terminal to backside	10.0			mm
$V_{ISOL}$	isolation voltage	t = 1 second t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000 2500			V

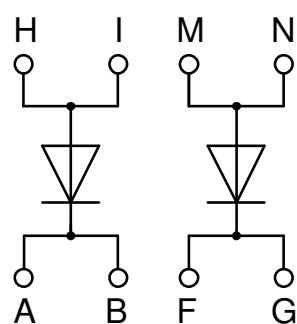
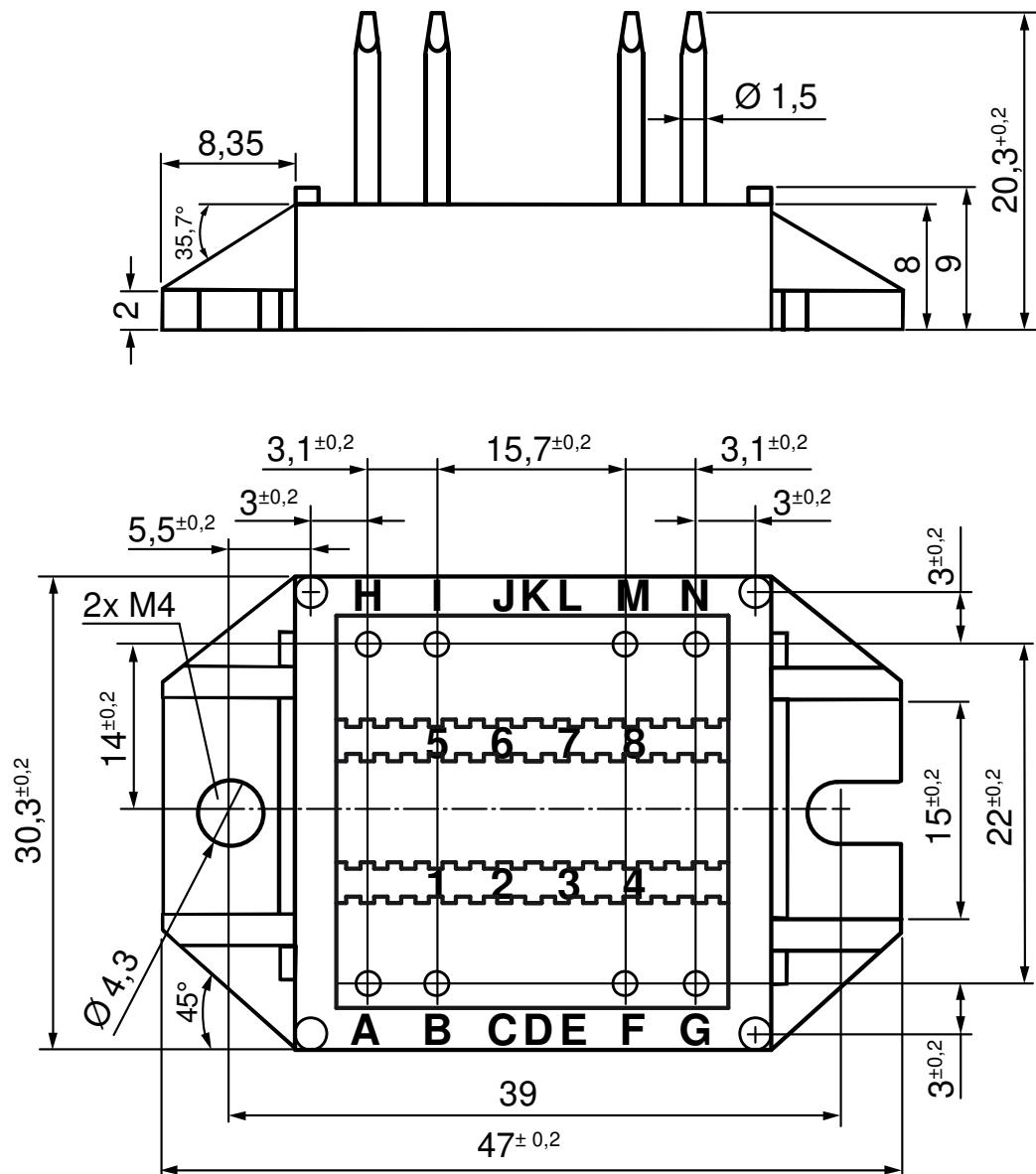


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEI2x61-06P	DSEI2x61-06P	Box	25	490784

**Equivalent Circuits for Simulation**
<sup>\*</sup>on die level

 $T_{VJ} = 150^\circ\text{C}$ 

	$V_0$	$R_0$	Fast Diode	
$V_{0\ max}$	threshold voltage	1.16		V
$R_{0\ max}$	slope resistance *	3.3		$\text{m}\Omega$

**Outlines ECO-PAC1**


### Fast Diode

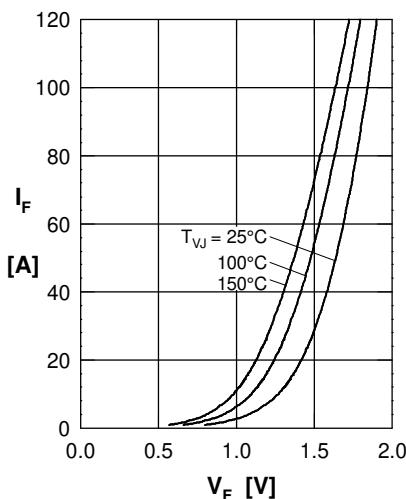


Fig. 1 Forward current  $I_F$  versus  
max. forward voltage drop  $V_F$

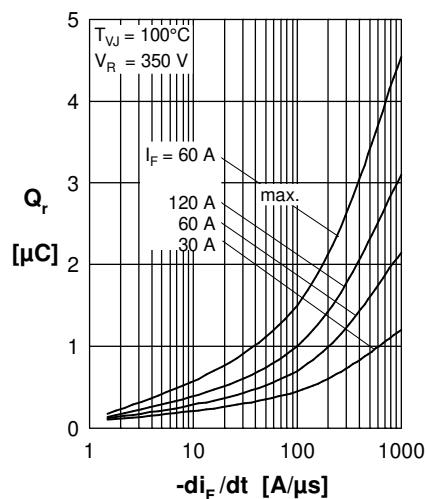


Fig. 2 Typ. reverse recov. charge  $Q_r$  versus  $-di_F/dt$

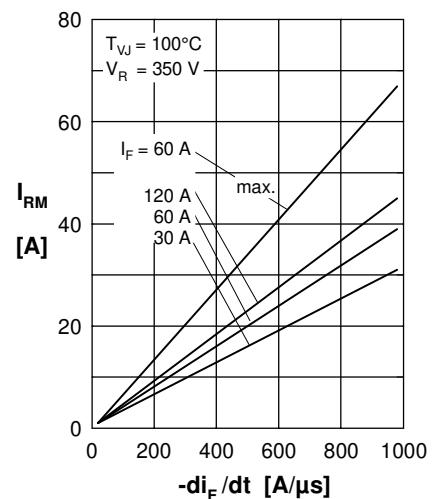


Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$

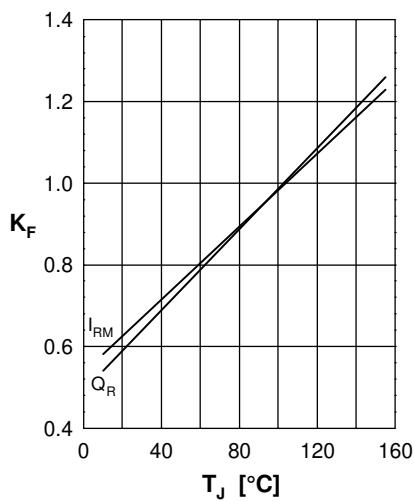


Fig. 4 Dynamic parameters  
 $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

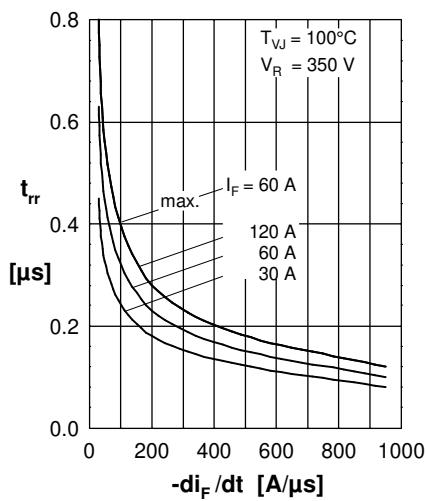


Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$

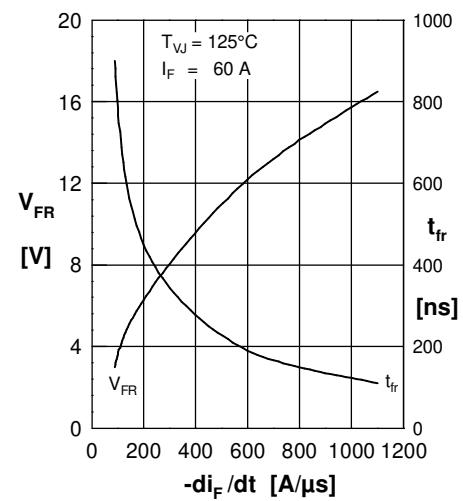


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $-di_F/dt$

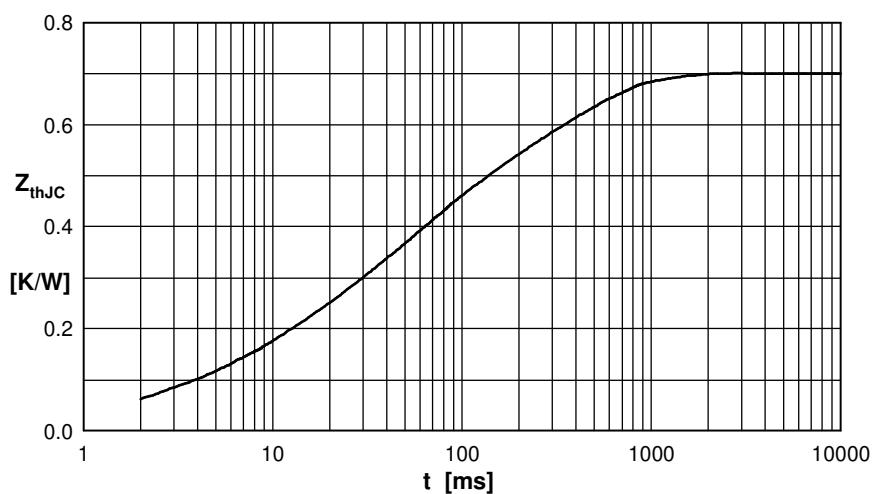


Fig. 7 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.120	0.010
2	0.045	0.002
3	0.105	0.050
4	0.160	0.050
5	0.270	0.350